imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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Obsolete



Micro Commercial Components

Micro Commercial Components 20736 Marilla Street Chatsworth CA 91311 Phone: (818) 701-4933 Fax: (818) 701-4939

TSMBJ1009C-130

Features

- Oxide-Glass passivated Junction
- Bi-Directional protection in a single device
- Surge capabilities up to 100A@10/1000us or 400A@8/20us
- High Off-State impedance and Low On-State voltage
- Plastic material has UL flammability classification 94V-0

Mechanical Data

- Case : Molded plastic
- Polarity : None cathode band denotes
- Approx Weight : 0.093grams

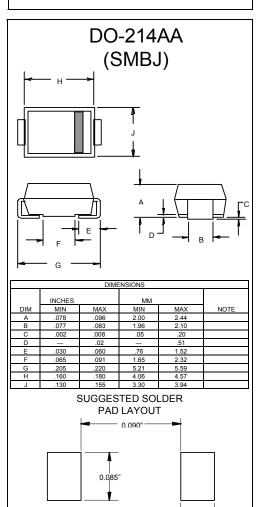
Maximum Ratings

Characteristic	Symbol	Value	Unit
Non-repetitive peak impulse current	PP	100A	10/1000us
Non-repetitive peak On-state current	I _{TSM}	50A	8.3ms, one-half cvcle
Operating temperature range	T _{OP}	-40~150°C	
Junction and storage temperature range	T _J , T _{stg}	-55~150°C	

Thermal Resistance

Characteristic	Symbol	Value	Unit
Thermal Resistance junction to lead	$R_{ extsf{ heta}JL}$	20°C/W	
Thermal Resistance junction to ambient	$R_{\theta}JA$	100°C/W	On recommended pad layout
Typical positive temperature coefficient for breakdown voltage	∆V _{BR} /∆Tj	0.1%/℃	

Transient Voltage Protection Device 120 Volts



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0.070"

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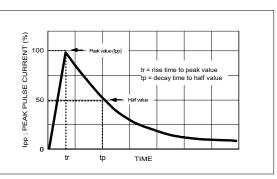
ELECTRICAL CHARACTERISTIC @25°C Unless otherwise specified

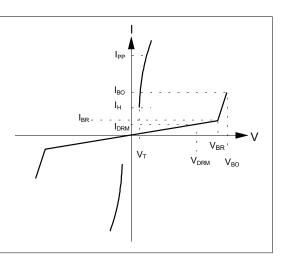
Parameter	Rated Repetitive Off -state Voltage	0	Breakover Voltage	On-State Voltage @I _T =1.0A	Breakover Current	Holding Current	Off-State
Symbol	V _{DRM}	I _{DRM}	V _{BO}	VT	I _{BO+}	I _H	CJ
Units	Volts	uA	Volts	Volts	mA	mA	pF
Limit	Max	Max	Max	Max	Max	Min	Тур.
TSMBJ1009C-130	120	5	160	5	800	150	120

MAXIMUM RATED SURGE WAVEFORM

Waveform	Standard	lpp (A)
2/10 us	GR-1089-CORE	500
8/20 us	IEC 61000-4-5	400
10/160 us	FCC Part 68	200
10/700 us	ITU-T K20/21	200
10/560 us	FCC Part 68	150
10/1000 us	GR-1089-CORE	100

Symbol	Parameter		
V _{DRM}	Stand-off voltage		
I _{DRM}	Leakage current at stand-off voltage		
V _{BR}	Breakdown voltage		
I _{BR}	Breakdown current		
V _{BO}	Breakover voltage		
I _{BO}	Breakover current		
l _H	Holding current	NOTE: 1	
VT	On state voltage		
I _{PP}	Peak pulse current		
Co	Off-state capacitance	NOTE: 2	





NOTE :

1. I $_H$ > (V $_L$ / R $_L$) If this criterion is not obeyed, the TSPD triggers but does not return correctly to high-resistance state.

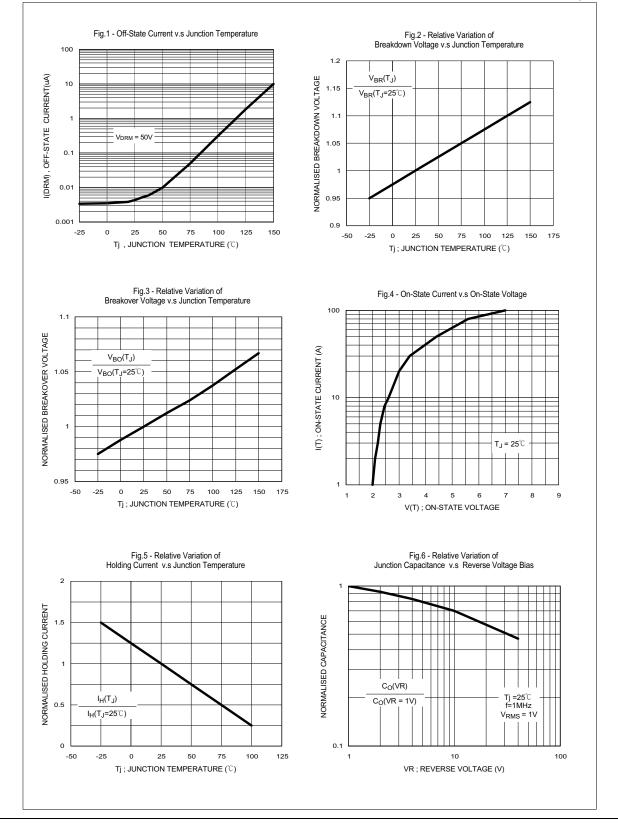
The surge recovery time. It does not exceed 30ms.

2. Off-state capacitance measured at f=1.0MHz , 1.0Vrms signal , VR=2Vdc bias.

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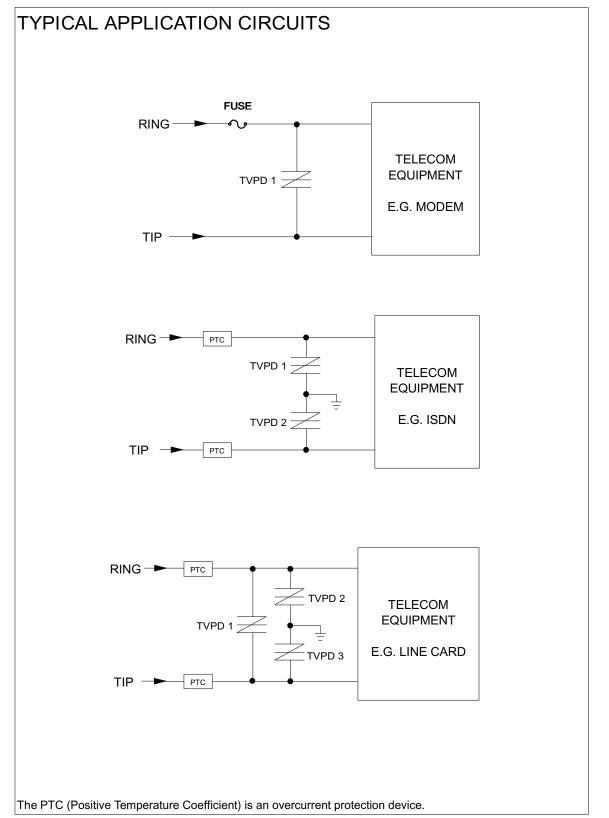


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